



DOCUMENT CHANGE REQUEST

DCR number 39

Changes required for: General

Originator: Jefferey

Date: 2003/03/13

Date sent: 2003/03/13

Organisation: -ESTEC

Status: IMPLEMENTED

Title: Transistors Microwave Metal Semiconductor Field Effect Power Gallium Arsenide, based on types

Number: 5614/006

Issue: 1

Other documents affected:

Page:

Paragraph:

Original wording:

Proposed wording:

Justification:

Attachments:

N/A

Modifications:

N/A

Approval signature:

Date signed:

2003-03-13